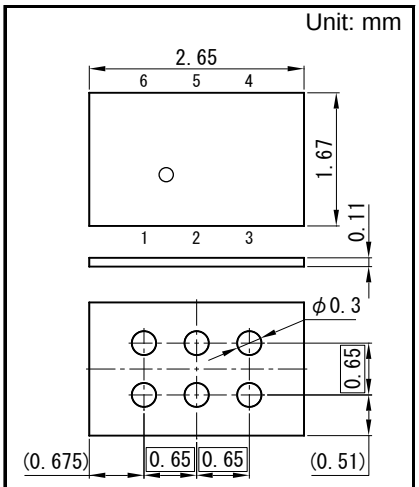
MOS FET

Panasonic FC6B22160L1

FC6B22160L1

Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits



1. Source1-1 (FET1)
2. Gate1 (FET1)
3. Source1-2 (FET1)
4. Source2-1 (FET2)
5. Gate2 (FET2)
6. Source2-2 (FET2)

Panasonic	MLGA006-W-1727-RB
JEITA	—
Code	—

■ Features

- Low source-source ON resistance:Rss(on) typ. = 4.9 mΩ（VGS = 3.8 V)
- CSP(Chip Size Package)
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)

■ Marking Symbol: 36

■ Packaging

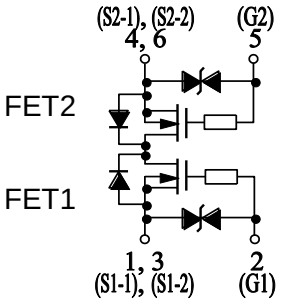
Embossed type (Thermo-compression sealing) : 1 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
Source-source Voltage		VSS	20	V
Gate-source Voltage		VGS	±8	V
Source Current	DC *1	IS1	8	A
	DC *2	IS2	17	A
	Pulse *3	ISp	80	A
Total Power Dissipation	DC *1	PD1	0.45	W
	DC *2	PD2	2.1	W
Channel Temperature		Tch	150	°C
Storage Temperature Range		Tstg	-55 to +150	°C
Thermal Resistance (ch-a)	DC *1	Rth1	278	°C/W
	DC *2	Rth2	59	°C/W

Note *1 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm)
using the minimum recommended pad size (36μm Copper).
*2 Mounted on Ceramic substrate (70 mm × 70 mm × t1.0 mm).
*3 t = 10 μs, Duty Cycle ≤ 1 %

Equivalent circuit



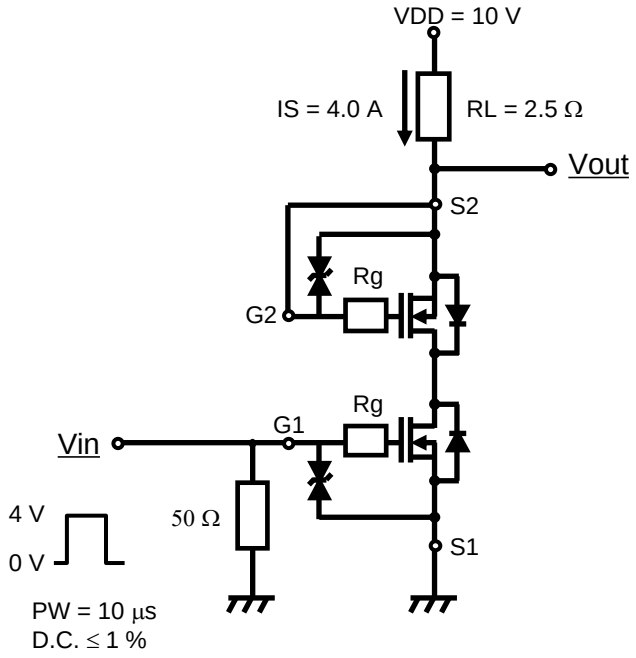
Established : 2015-10-23
Revised : ####-##-##

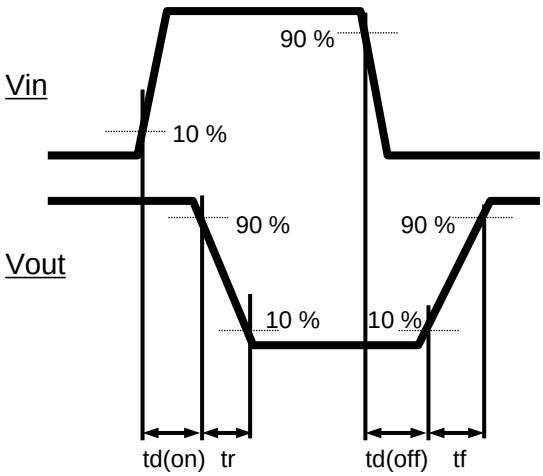
■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	20			V
Zero Gate Voltage Source Current	ISSS	VSS = 20 V, VGS = 0 V			1.0	μA
Gate-source Leakage Current	IGSS	VGS = ±8 V, VSS = 0 V			±10	μA
		VGS = ±5 V, VSS = 0 V			±1.0	
Gate-source Threshold Voltage	Vth	IS = 1.1 mA, VSS = 10 V	0.35	0.90	1.4	V
Source-source On-state Resistance	RSS(on)1	IS = 4.0 A, VGS = 4.5 V	3.5	4.7	6.2	mΩ
	RSS(on)2	IS = 4.0 A, VGS = 4.0 V	3.6	4.8	6.4	
	RSS(on)3	IS = 4.0 A, VGS = 3.8 V	3.7	4.9	6.6	
	RSS(on)4	IS = 4.0 A, VGS = 3.1 V	3.9	5.2	8.6	
	RSS(on)5	IS = 4.0 A, VGS = 2.5 V	4	6	11.8	
Body Diode Forward Voltage	VF(s-s)	IF = 4.0 A, VGS = 0 V		0.8	1.2	V
Input Capacitance *1	Ciss	VSS = 10 V, VGS = 0 V, f = 1 MHz		3250		pF
Output Capacitance *1	Coss			290		
Reverse Transfer Capacitance *1	Crss			250		
Turn-on delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4.0 V		1.2		μs
Rise Time *1,*2	tr	IS = 4.0 A		2.4		
Turn-off delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4.0 to 0 V		8.1		μs
Fall Time *1,*2	tf	IS = 4.0 A		3.9		
Total Gate Charge *1	Qg	VDD = 10 V		35		nC
Gate-source Charge *1	Qgs	VGS = 0 to 4.0 V,		5		
Gate-drain Charge *1	Qgd	IS = 4.0 A		10		

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.
*1 Guaranteed by design, not subject to production testing
*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

Note2 : Measurement circuit





Established : 2015-10-23
Revised : ####-##-##

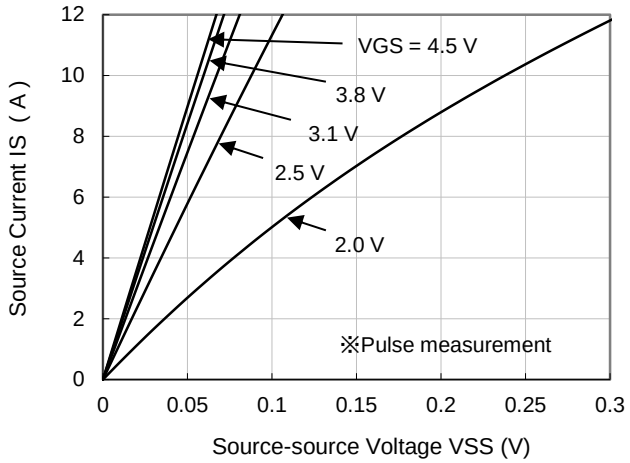
MOS FET

Panasonic

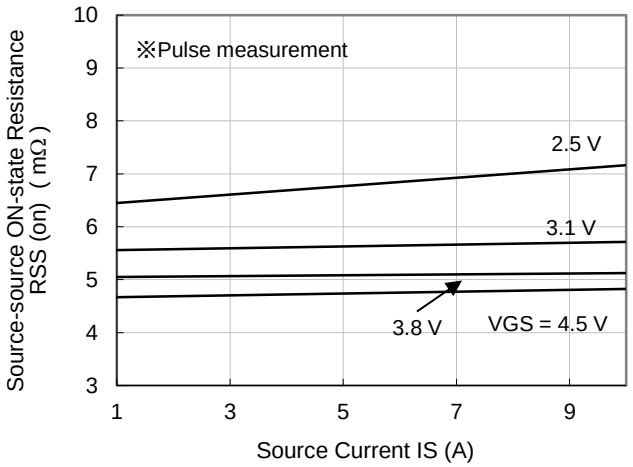
FC6B22160L1

Technical Data (reference)

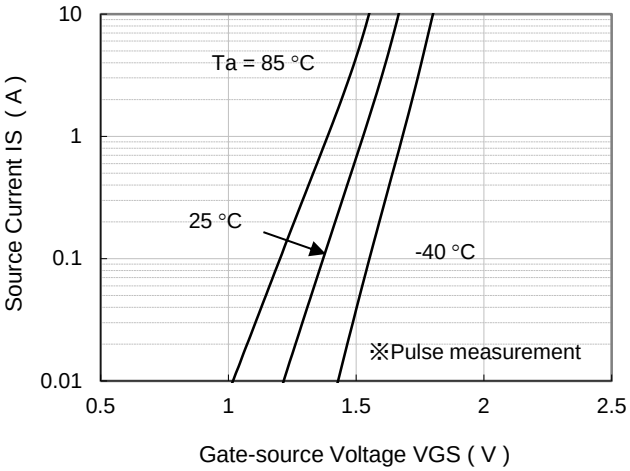
IS - VSS



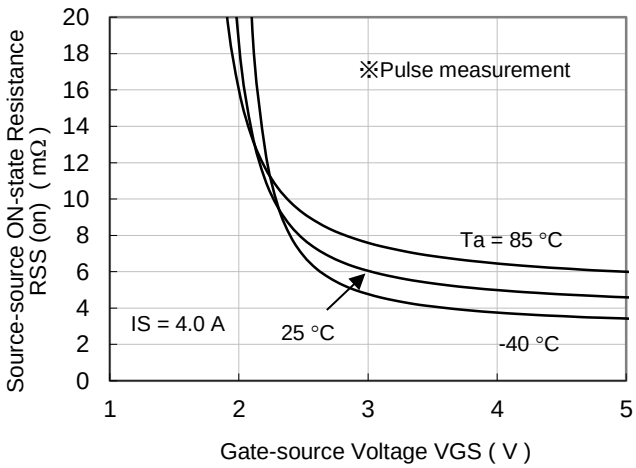
RSS(on) - IS



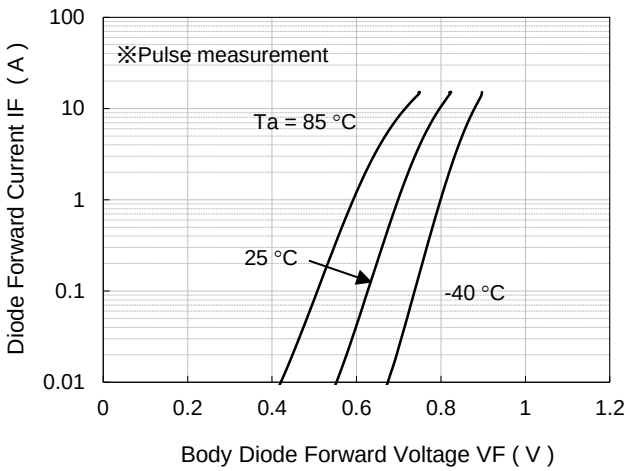
IS - VGS



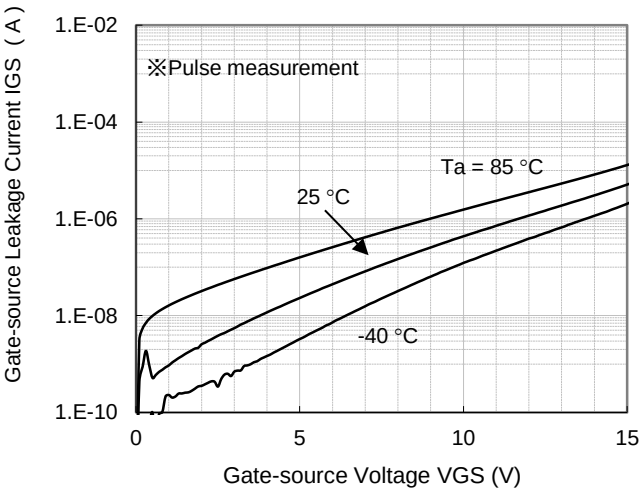
RSS(on) - VGS



IF - VF



IGS - VGS



Established : 2015-10-23
Revised : ####-##-##

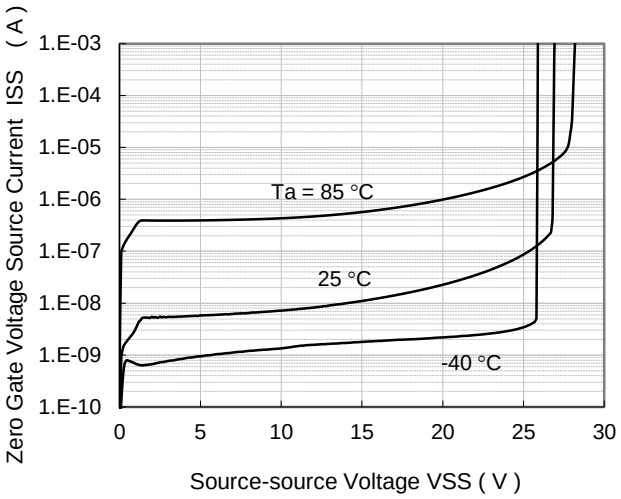
MOS FET

Panasonic

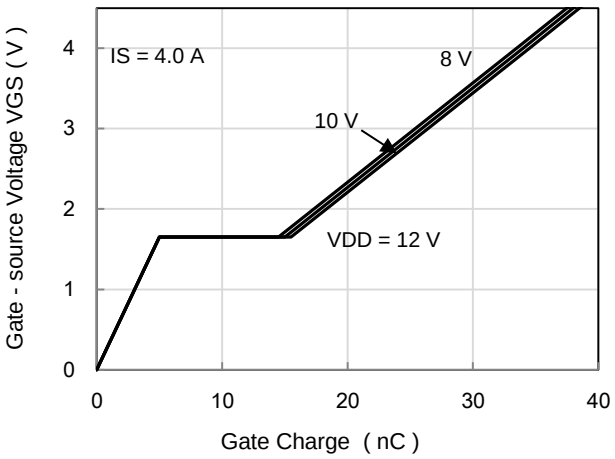
FC6B22160L1

Technical Data (reference)

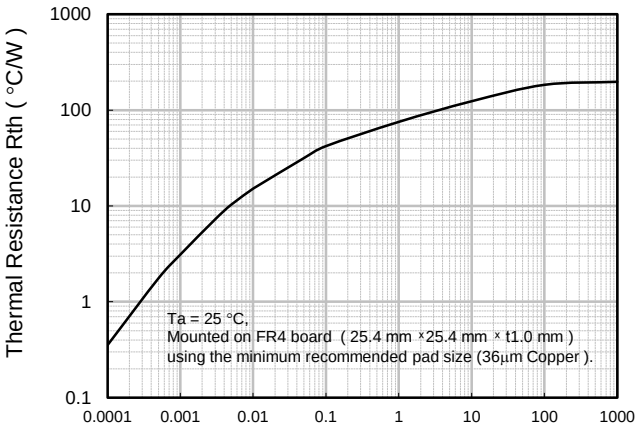
ISS - VSS



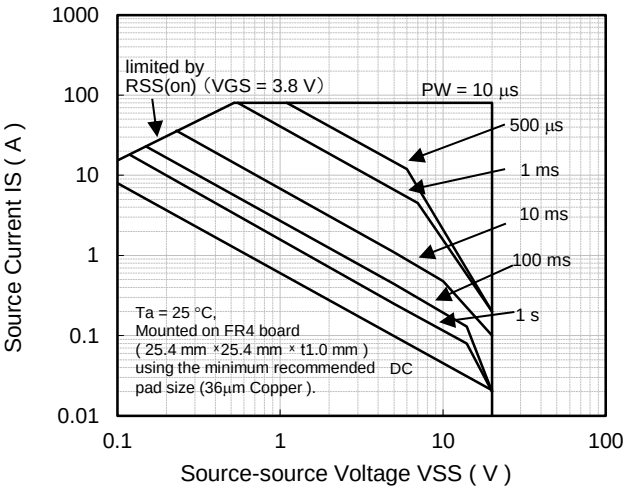
Dynamic Input/Output Characteristics



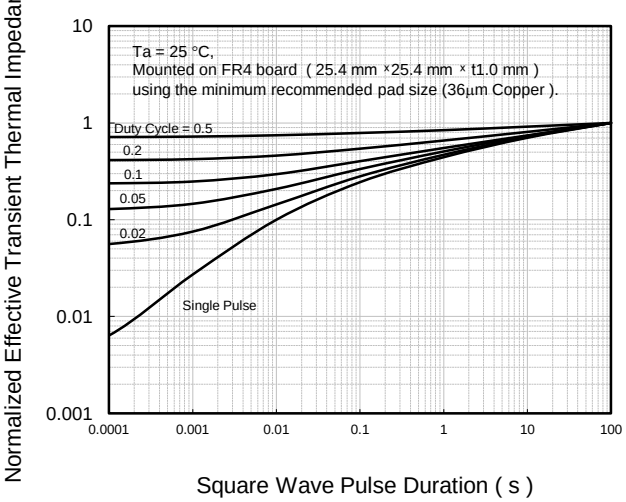
Rth - tsw



Safe Operating Area



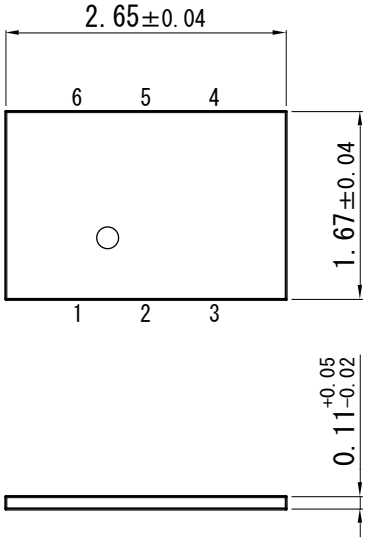
Thermal Response

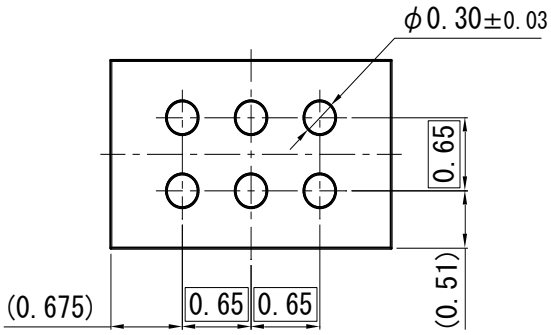


Established : 2015-10-23
Revised : ####-##-##

■ Outline (MLGA006-W-1727-RB)

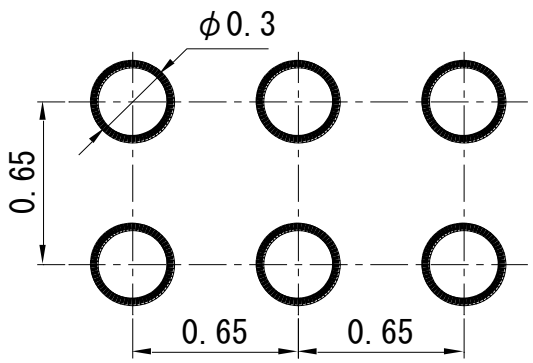
Unit: mm





■ Land Pattern (Reference)

Unit: mm



Established : 2015-10-23
Revised : ####-##-##

Request for your special attention and precautions in using the technical information and semiconductors described in this book

(1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.

(2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.

(3) The products described in this book are intended to be used for general applications (such as office equipment, communications equipment, measuring instruments and household appliances), or for specific applications as expressly stated in this book.
Consult our sales staff in advance for information on the following applications:
- Special applications (such as for airplanes, aerospace, automotive equipment, traffic signaling equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.

It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the products described in this book for any special application, unless our company agrees to your using the products in this book for any special application.

(4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.

(5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

(6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.

20100202

单击下面可查看定价，库存，交付和生命周期等信息

>>Panasonic(松下)